# DG447, DG448



**Vishay Siliconix** 

# Low Power, High Voltage SPST Analog Switches

### DESCRIPTION

The DG447, DG448 dual are supply single-pole/single-throw (SPST) switches. On resistance is 25  $\Omega$  maximum and flatness is 2.2  $\Omega$  max over the specified analog signal range. These analog switches were designed to provide high speed, low error switching of precision analog signals. The primary application areas are in the routing and switching in telecommunications and test equipment. Combining low power, low leakages, low on-resistance and small physical size, the DG477, DG448 are also ideally suited for portable and battery powered industrial and military equipment.

The DG477 has one normally closed switch, while the DG448 switch is normally open. They operate either from a single 7 V to 36 V supply or from dual  $\pm$  4.5 V to  $\pm$  20 V supplies. They are offered in the very popular, small TSOP6 package.

### BENEFITS

- Wide dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- · Improved reliability

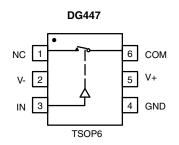
## FEATURES

- ± 15 V analog signal range
- On-resistance R<sub>DS(on)</sub>: 25 Ω max.
- Fast switching action ton: 100 ns
- V<sub>L</sub> logic supply not required
- TTL CMOS input compatible
- · Rail to rail signal handling
- · Dual or single supply operation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

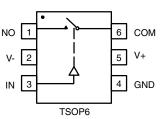
### **APPLICATIONS**

- Precision test equipment
- · Precision instrumentation
- · Communications systems
- PBX, PABX systems
- Audio equipment
- Redundant systems
- PC multimedia boards
- Hard disc drives

## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION







TRUTH TABLE					
LOGIC	DG447	DG448			
0	On	Off			
1	Off	On			

#### Note

 Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

Device Marking: DG447DV = G5xxx DG448DV = G6xxx

ORDERING INFORMATION				
TEMP. RANGE	PACKAGE	PART NUMBER		
DG447, DG448				
-40 °C to +85 °C		DG447DV-T1-E3		
	6-pin TSOP	DG448DV-T1-E3		

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DG447, DG448

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ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)					
PARAMETER		LIMIT	UNIT		
V+		44			
GND		25	V		
Digital inputs <sup>a</sup> , V <sub>NO/NC</sub> , V <sub>COM</sub>		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first			
Continuous current (any terminal)		30	<b>m</b> (		
Current (NO or NC or COM) pulsed at 1 ms, 10 % duty cycle		100	mA		
Storage temperature		-65 to +150	°C		
Power dissipation (package) <sup>b</sup>	6-pin TSOP <sup>c</sup>	570	mW		

Notes

a. Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings

b. All leads welded or soldered to PC board
c. Derate 7 mW/°C above 70 °C

SPECIFICATIONS <sup>a</sup>							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED	TEMP. <sup>b</sup>	D SUFFIX -40 °C TO +85 °C			UNIT
		V+ = 15 V, V- = -15 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup>		MIN. <sup>d</sup>	TYP. °	MAX. d	0
Analog Switch			•			•	
Analog signal range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-15	-	15	V
Drain-source on-resistance	R <sub>ON</sub>	$I_{NO/NC}$ = 10 mA, $V_{COM}$ = 10 V,	Room	-	17	25	
	PON	V+ = 13.5 V, V- = -13.5 V	Full	-	-	30	Ω
On-resistance flatness	R <sub>ON</sub>	$I_{NO/NC} = 10 \text{ mA}, V_{COM} = \pm 5 \text{ V}, 0 \text{ V},$	Room	-	0.8	2.2	52
On-resistance hatness	flatness	V+ = 13.5 V, V- = -13.5 V	Full	-	-	3	
			Room	-1	-0.1	1	
	I <sub>NO/NC(off)</sub>	$V_{+} = 16.5, V_{-} = -16.5 V_{,}$	Full	-10	-	10	
Switch off leakage current		V <sub>COM</sub> = ± 15.5 V, V <sub>NO/NC</sub> = -/+ 15.5 V	Room	-1	-0.1	1	
	I <sub>COM(off)</sub>		Full	-10	-	10	nA
		V+ = 16.5 V, V- = -16.5 V,	Room	-1	-0.1	1	
Channel on leakage current	I <sub>COM(on)</sub>	$V_{COM} = V_{NO/NC} = \pm 15.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input, high voltage	I <sub>INH</sub>		Full	2.4	-	-	
Input, low voltage	I <sub>INL</sub>		Full	-	-	0.8	V
Input capacitance e	C <sub>IN</sub>		Room	-	5	-	pF
Input current	I <sub>IN</sub>	$V_{IN} = 0 V \text{ or } 5 V$		-1	-	1	μA
Dynamic Characteristics	<u> </u>		•				•
Turn-on time	+		Room	-	100	130	- ns
Turn-on time	t <sub>on</sub>	$R_{L} = 300 \ \Omega, C_{L} = 35 \ pF$	Full	-	-	140	
Turne off time o		$V_{NO/NC} = \pm 10 V$	Room	-	50	95	
Turn-off time	t <sub>off</sub>		Full	-	-	110	
Charge injection <sup>e</sup>	Q	$C_L$ = 10 nF, $V_{gen}$ = 0 V, $R_{gen}$ = 0 $\Omega$	Room	-	10	-	рС
Off-isolation <sup>e</sup>	OIRR	$C_L$ = 5 pF, $R_L$ = 50 $\Omega$ , f = 1 MHz	Room	-	-72	-	dB
Source off capacitance e	C <sub>S(off)</sub>	£ 1 MIL	Room	-	19	-	pF
Drain off capacitance <sup>e</sup>	C <sub>D(off)</sub>	f = 1 MHz	Room	-	8	-	
Channel on capacitance <sup>e</sup>	C <sub>D(on)</sub>	f = 1 MHz	Room	-	30	-	
Power Supplies	<u> </u>		•				
Desitive surgely surgest			Room	-	16	30	
Positive supply current	I+	V+ = 16.5 V, V- = -16.5 V,	Full	-	-	50	
Niccoll and a start		$V_{IN} = 0 V \text{ or } 5 V$	Room	-1	-0.02	-	μA
Negative supply current	I-		Full	-10	-	-	1

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# **Vishay Siliconix**

SPECIFICATIONS <sup>a</sup>							
PABAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED	TEMP. <sup>b</sup>	D SUFFIX - 40 °C TO +85 °C			UNIT
		V+ = 12 V, V- = 0 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup>		MIN. <sup>d</sup>	۲YP. ۵	MAX. d	
Analog Switch							
Analog signal range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	12	V
Drain-source on-resistance	Paul	$R_{ON} = -10 \text{ mA}, V_{COM} = 8 \text{ V}, V_{COM} = 10.8 \text{ V}$	Room	-	32	45	Ω
Drain-source on-resistance	non		Full	-	-	60	
On-resistance flatness	R <sub>ON</sub>	I <sub>NO/NC</sub> = 10 mA, V <sub>COM</sub> = 2 V, 6 V, 8 V	Room	-	2	6	
On-resistance natness	flatness	V+ = 10.8 V	Full	-	-	8	
Dynamic Characteristics							
Turn-on time	t <sub>on</sub>		Room	-	140	175	- ns
	Lon	$V_{NO, NC} = \pm 10 \text{ V}, \text{ R}_{L} = 300 \Omega, \text{ C}_{L} = 35 \text{ pF}$	Full	-	-	225	
Turn-off time	<b>t</b>	$v_{\rm NO, NC} = \pm 10 v, n_{\rm L} = 300 s_2, O_{\rm L} = 35  {\rm pr}$	Room	-	50	120	115
	t <sub>off</sub>		Full	-	-	150	
Charge injection <sup>e</sup>	Q	$C_L$ = 10 nF, $V_{gen}$ = 0 V, $R_{gen}$ = 0 $\Omega$	Room	-	12	-	рС
Power Supplies							
Positive supply current	+	V+ = 13.2 V, V <sub>IN</sub> = 0 V, 5 V	Room	-	22	50	ıΔ
r ostive supply current	17	$v_{\rm T} = 10.2  v,  v_{\rm IN} = 0  v,  0  v$	Full	-	-	75	μA

#### Notes

a. Refer to PROCESS OPTION FLOWCHART

b. Room = 25 °C, full = as determined by the operating temperature suffix

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet

e. Guaranteed by design, not subject to production test

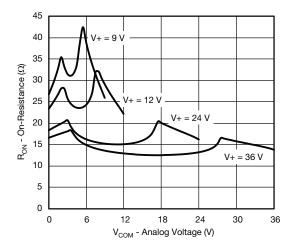
f.  $V_{IN}$  = input voltage to perform proper function

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

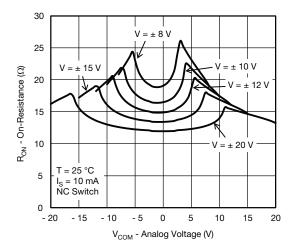


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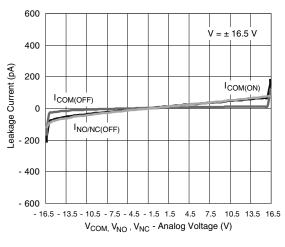
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



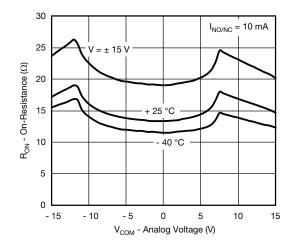
RON vs. VCOM and Single Supply Voltage



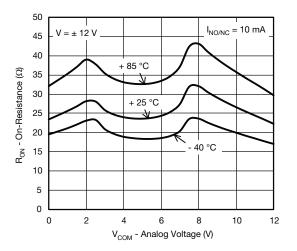
 $R_{\text{ON}}$  vs.  $V_{\text{COM}}$  and Dual Supply Voltage



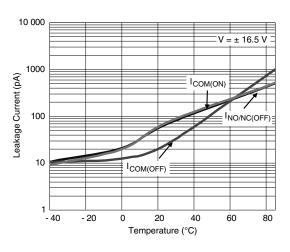
Leakage vs. Analog Voltage



R<sub>ON</sub> vs. Analog Voltage and Temperature



R<sub>ON</sub> vs. Analog Voltage and Temperature



Leakage Current vs. Temperature

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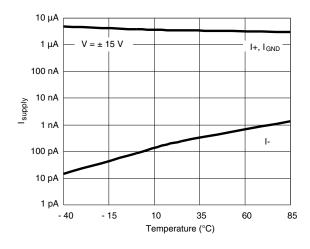
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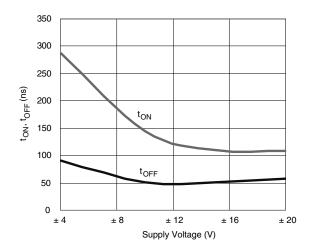


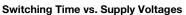
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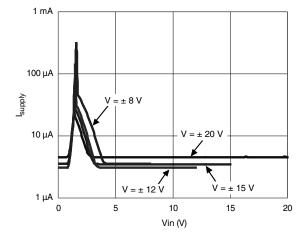


Supply Current vs. Temperature

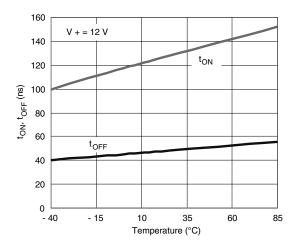




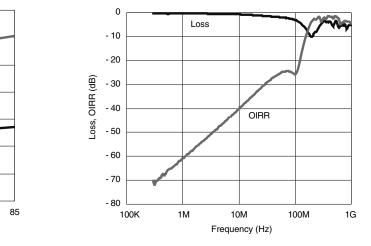
ton



Supply Current vs. VIN



Switching Time vs. Temperature



Switching Time vs. Temperature

Temperature (°C)

10

35

60

Off Isolation and Insertion Loss vs. Frequency

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140

120

100

80

60

40

20

0

- 40

t<sub>ON</sub>, t<sub>OFF</sub> (ns)

V = +15 V

tOFF

- 15

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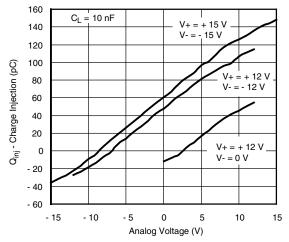
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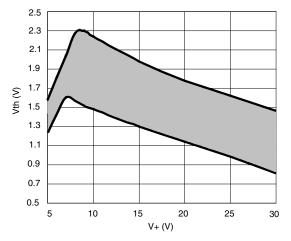


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## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



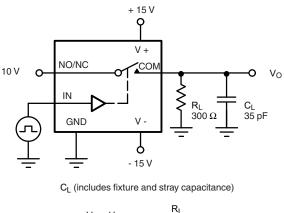
Charge Injection vs. Analog Voltage (Measured at COM pin)



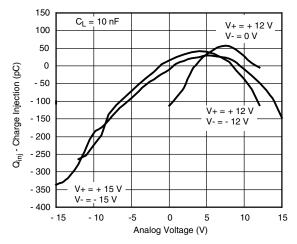
Input Switching Threshold vs. Supply Voltage

### **TEST CIRCUITS**

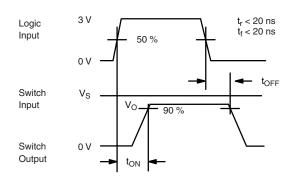
V<sub>O</sub> is the steady state output with the switch on.



$$V_{\rm O} = V_{\rm S} - \frac{R_{\rm L}}{R_{\rm L} + r_{\rm ON}}$$



Charge Injection vs. Analog Voltage (Measured at NC or NO pin)



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

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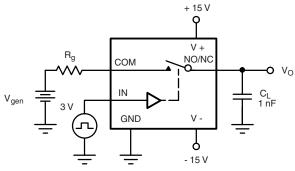
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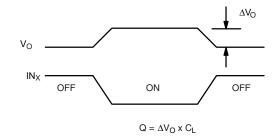
**o** v<sub>o</sub>

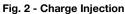
 $\mathsf{R}_\mathsf{L}$ 

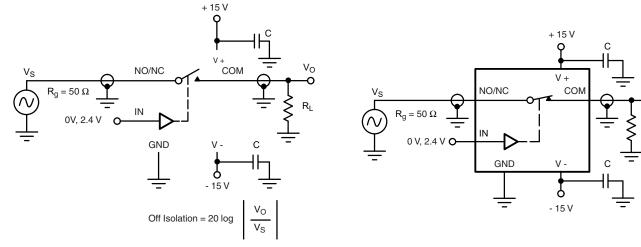
## **TEST CIRCUITS**

 $V_{\text{O}}$  is the steady state output with the switch on.









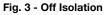


Fig. 4 - Insertion Loss

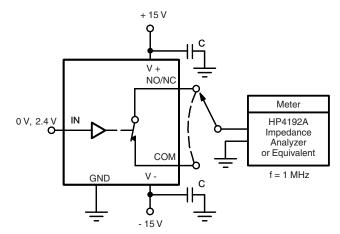


Fig. 5 - Source/Drain Capacitances



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<b>PRODUCT SUMMARY</b>		
Part number	DG447	DG448
Status code	2	2
Configuration	SPST x 1, NO	SPST x 1, NO
Single supply min. (V)	7	7
Single supply max. (V)	36	36
Dual supply min. (V)	4.5	4.5
Dual supply max. (V)	22	22
On-resistance (Ω)	32	32
Charge injection (pC)	12	12
Source on capacitance (pF)	30	30
Source off capacitance (pF)	8	8
Leakage switch on typ. (nA)	0.1	0.1
Leakage switch off max. (nA)	1	1
-3 dB bandwidth (MHz)	-	-
Package	TSOP-6	TSOP-6
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare
Interface	Parallel	Parallel
Single supply operation	Yes	Yes
Dual supply operation	Yes	Yes
Turn on time max. (ns)	130	130
Crosstalk and off isolation	-72	-72

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Package Information

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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C









6-LEAD TSOP



	MIL	LIMETER	RS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
<b>A</b> <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004	
A <sub>2</sub>	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		0.0374 BSC			
<b>e</b> <sub>1</sub>	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L <sub>1</sub>	0.60 Ref			0.024 Ref			
L <sub>2</sub>	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
$\theta_1$		7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							



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